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**Product data sheet** 

### 1. Product profile

### 1.1 General description

Planar PIN diode in a SOD882D leadless ultra small plastic SMD package.

#### 1.2 Features and benefits

- High voltage, current controlled
- Low diode capacitance
- Low diode forward resistance (low loss)
- Very low series inductance
- RF resistor for RF switches

### 1.3 Applications

- RF attenuators and switches
- Band switch for TV tuners
- Series diode for mobile communication transmit-receive switch

## 2. Pinning information

Table 1. Discrete pinning

ziooroto piiiiiig	
Description	Simplified outline Symbol
cathode	[1]
anode	
	Transparent sym006 top view
	<b>Description</b> cathode

<sup>[1]</sup> The marking bar indicates the cathode.

## 3. Ordering information

Table 2. Ordering information

Type number	r Package			
	Name	Description	Version	
BAP65LX	DFN1006D-2	leadless ultra small plastic package; 2 terminals; body 1 $\times$ 0.6 $\times$ 0.4 mm	SOD882D	



Silicon PIN diode

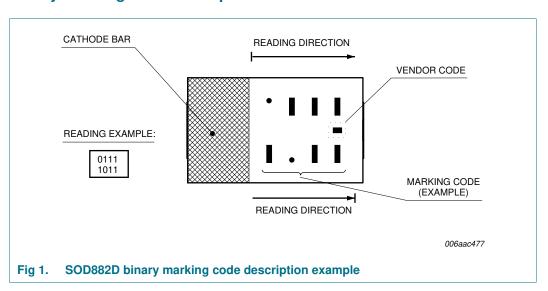
## 4. Marking

Table 3. Marking codes

Type number	Marking code <sup>[1]</sup>
BAP65LX	1001
	0110

<sup>[1]</sup> For SOD882D binary marking code description, see Figure 1.

### 4.1 Binary marking code description



## 5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_R$	reverse voltage		-	30	V
I <sub>F</sub>	forward current		-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> = 90 °C	-	135	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>i</sub>	junction temperature		-65	+150	°C

### 6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j\text{-sp})}$	thermal resistance from junction to solder point		78	K/W

**BAP65LX** 

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## 7. Characteristics

Table 6. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{F}$	forward voltage	$I_F = 50 \text{ mA}$	-	0.9	1.1	V
I <sub>R</sub>	reverse current	$V_R = 20 \text{ V}$	-	-	20	nA
C <sub>d</sub>	diode capacitance	see Figure 2; f = 1 MHz;				
		$V_R = 0 V$	-	0.61	-	рF
		$V_R = 1 V$	-	0.48	0.85	рF
		$V_R = 3 V$	-	0.43	0.7	рF
		V <sub>R</sub> = 20 V	-	0.37	-	рF
r <sub>D</sub>	diode forward resistance	see Figure 3; f = 100 MHz;				
		I <sub>F</sub> = 1 mA	-	0.94	-	Ω
		I <sub>F</sub> = 5 mA	-	0.58	0.95	Ω
		I <sub>F</sub> = 10 mA	-	0.49	0.9	Ω
		I <sub>F</sub> = 100 mA	-	0.35	-	Ω
ISL	isolation	see Figure 4; V <sub>R</sub> = 0 V;				
		f = 900 MHz	-	10	-	dB
		f = 1800 MHz	-	5.5	-	dB
		f = 2450 MHz	-	3.9	-	dB
L <sub>ins</sub>	insertion loss	see Figure 5; I <sub>F</sub> = 1 mA;				
		f = 900 MHz	-	0.09	-	dB
		f = 1800 MHz	-	0.09	-	dB
		f = 2450 MHz	-	0.10	-	dB
L <sub>ins</sub>	insertion loss	see Figure 5; I <sub>F</sub> = 5 mA;				
		f = 900 MHz	-	0.06	-	dB
		f = 1800 MHz	-	0.07	-	dB
		f = 2450 MHz	-	0.08	-	dB
L <sub>ins</sub>	insertion loss	see Figure 5; I <sub>F</sub> = 10 mA;				
		f = 900 MHz	-	0.06	-	dB
		f = 1800 MHz	-	0.07	-	dB
		f = 2450 MHz	-	0.08	-	dB
L <sub>ins</sub>	insertion loss	see Figure 5; I <sub>F</sub> = 100 mA;				
		f = 900 MHz	-	0.05	-	dB
		f = 1800 MHz	-	0.06	-	dB
		f = 2450 MHz	-	0.07	-	dB
$\tau_{L}$	charge carrier life time	when switched from I $_{F}$ = 10 mA to I $_{R}$ = 6 mA; R $_{L}$ = 100 $\Omega;$ measured at I $_{R}$ = 3 mA	-	0.18	-	μS
L <sub>S</sub>	series inductance	I <sub>F</sub> = 100 mA; f = 100 MHz	-	0.4	-	nH

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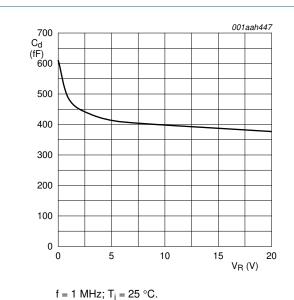
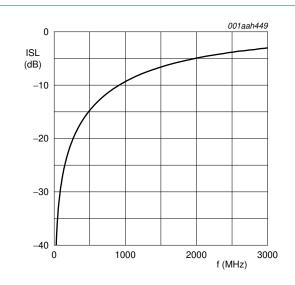


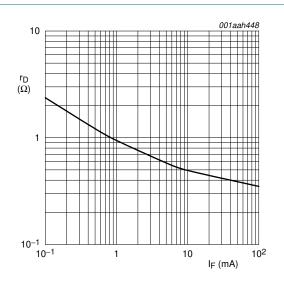
Fig 2. Diode capacitance as a function of reverse voltage; typical values



T<sub>amb</sub> = 25 °C

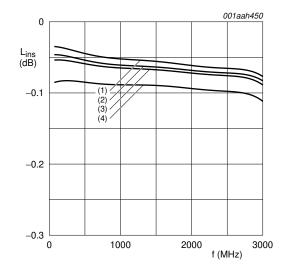
Diode zero biased and inserted in series with a 50  $\Omega$  stripline circuit





f = 100 MHz;  $T_i = 25 \,^{\circ}\text{C}$ .

Fig 3. Forward resistance as a function of forward current; typical values



T<sub>amb</sub> = 25 °C

- (1)  $I_F = 100 \text{ mA}$
- (2)  $I_F = 10 \text{ mA}$
- (3)  $I_F = 5 \text{ mA}$
- (4)  $I_F = 1 \text{ mA}$

Diode inserted in series with a 50  $\Omega$  stripline circuit and biased via the analyzer Tee network

Fig 5. Insertion loss of the diode as a function of frequency; typical values

## 8. Package outline

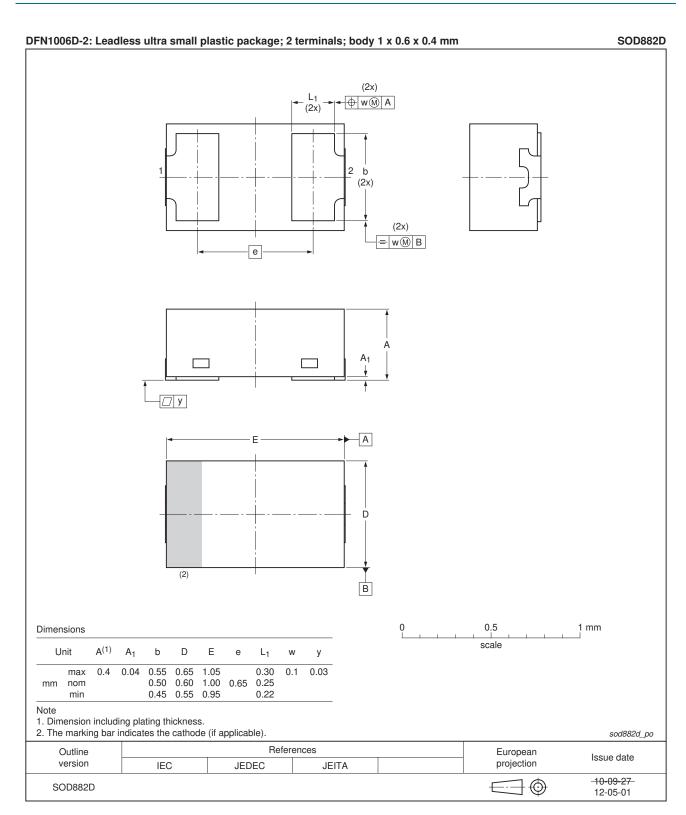


Fig 6. Package outline SOD882D (DFN1006D-2)

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Silicon PIN diode

## 9. Abbreviations

Table 7. Abbreviations

Acronym	Description
PIN	P-type, Intrinsic, N-type
SMD	Surface Mounted Device
RF	Radio Frequency

# 10. Revision history

#### Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BAP65LX v.2	20130807	Product data sheet	-	BAP65LX v.1		
Modifications:		on page 1: Changed packa	-			
	Table 2 on page 1: Changed package to SOD882D					
	<ul> <li>Section 4 on page 2: Update 'Marking' section</li> </ul>					
	Section 8 o	n page 5: Changed packag	e to SOD882D			
BAP65LX v.1	20071211	Product data sheet	-	-		

Silicon PIN diode

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#### 11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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